

# isc Silicon PNP Power Transistor

# 2SB1160

## DESCRIPTION

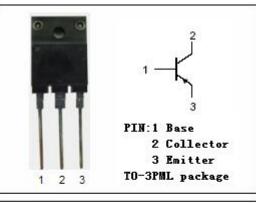
- Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -150V(Min)
- Good Linearity of  $h_{\text{FE}}$
- Wide Area of Safe Operation
- Complement to Type 2SD1715
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

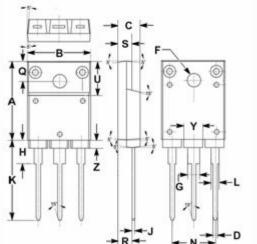
## APPLICATIONS

• Designed for high power amplifier applications

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-150	V	
Vceo	Collector-Emitter Voltage	-150	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-9	A	
I <sub>CP</sub>	Collector Current-Pulse	-15	А	
Pc	Collector Power Dissipation @ Tc=25℃	100	W	
	Collector Power Dissipation @ T <sub>a</sub> =25°C	3		
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	

# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





	m	m
DIM	MIN	MAX
Α	19.90	20.10
В	15.75	16.10
С	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
Η	5.90	6.10
J	0.595	0.70
К	21.10	22.50
L	1.90	2.25
Ν	10.80	11.00
0	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Y	4.20	4.90
Z	1.90	2.10

isc website: <u>www.iscsemi.com</u>



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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -0.7A			-2.0	V
V <sub>BE(on)</sub>	Base -Emitter On Voltage	I <sub>C</sub> = -7A; V <sub>CE</sub> = -5V			-1.8	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -150V; I <sub>E</sub> = 0			-50	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -3V; I <sub>C</sub> = 0			-50	μA
hfe-1	DC Current Gain	Ic= -20mA; Vce= -5V	20			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	60		200	
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = -7A; V <sub>CE</sub> = -5V	20			

### h<sub>FE-2</sub>Classifications

	A	
Q	s	Р
60-120	80-160	100-200

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